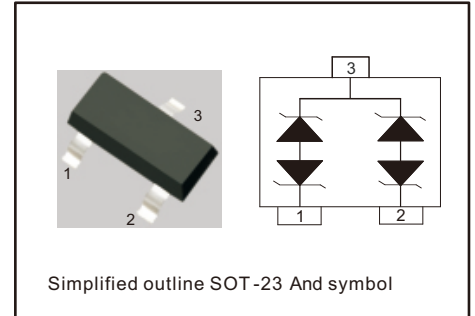




## Transient Voltage Suppressors for ESD Protection

### General Description

The ESDB18V0T2CA is designed to protect voltage sensitive components that require ultra-low capacitance from ESD and transient voltage events. Excellent clamping capability, low leakage, and fast response time, make these parts ideal for ESD protection on designs where board space is at a premium.



### FEATURES

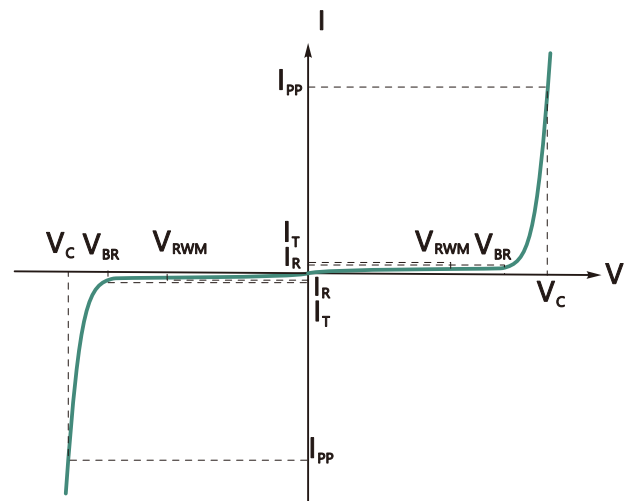
- Stand-off voltage: 18V Max.
- Transient protection for each line according to IEC61000-4-2(ESD):  $\pm 30\text{kV}$  (contact)  $\pm 30\text{kV}$  (air)  
IEC61000-4-4(Lightning): 10A (8/20 $\mu\text{s}$ )
- Ultra-low capacitance:  $C_j = 20\text{pF}$  typ.
- Low leakage current

### Applications

- Computers and peripherals;
- Audio and video equipment;
- Communication systems;
- Portable electronics.

### Electronics Parameter

Parameter	Symbol
Maximum Reverse Peak Pulse Current	$I_{PP}$
Clamping Voltage @ $I_{PP}$	$V_C$
Peak Reverse Working Voltage	$V_{RWM}$
Reverse Leakage Current @ $V_{RWM}$	$I_R$
Breakdown Voltage @ $I_T$	$V_{BR}$
Test Current	$I_T$





MAXIMUM RATINGS( $T_a=25^{\circ}\text{C}$  unless otherwise noted)

Parameter	Symbol	Value	Unit
Peak Pulse Power (8/20 $\mu\text{S}$ )	Ppk	350	W
Peak Pulse Current	Ipp	10	A
ESD per IEC 61000-4-2(Air)	VESD	$\pm 30$	KV
ESD per IEC 61000-4-2(Contact)		$\pm 30$	
Operating Temperature Range	TJ	-55~+125	$^{\circ}\text{C}$
Storage Temperature Range	Tstg	-55~+150	$^{\circ}\text{C}$

ELECTRICAL CHARACTERISTICS( $T_a=25^{\circ}\text{C}$  unless otherwise noted)

Parameter	Symbol	Test conditions	Min	Typ	Max	Unit
Reverse Stand-off Voltage	VRWM				18	V
Breakdown Voltage	VBR	IT=1mA	20.5		26	V
Reverse Leakage Current	IR	V=VRWM, $T_a=25^{\circ}\text{C}$			1	$\mu\text{A}$
Clamping Voltage	VC	IPP=1A, tp=8/20 $\mu\text{s}$		25		V
		IPP=10A, tp=8/20 $\mu\text{s}$			35	
Junction Capacitance	Cj	VR=0V , f=1MHz		20	50	pF



## Typical Characteristics

Fig.1 Clamping Voltage vs. Peak Pulse Current

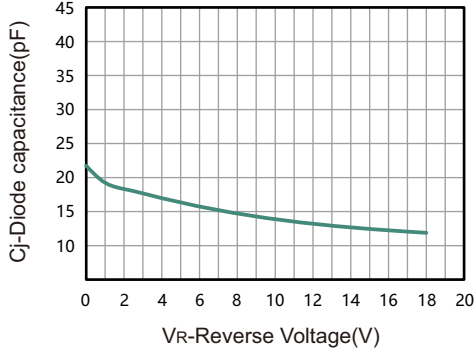


Fig.2 Clamping Voltage vs. Peak Pulse Current

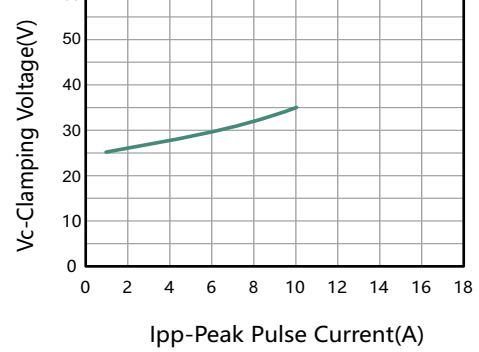


Fig.3 Non-repetitive peak pulse power vs. Pulse time

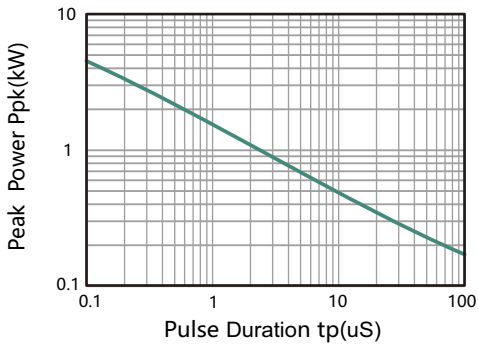


Fig.4 Power Derating Curve

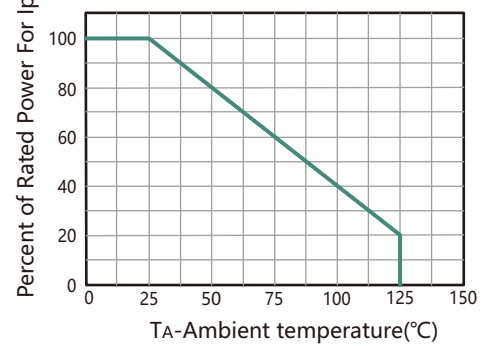


Fig.5 Pulse Waveform

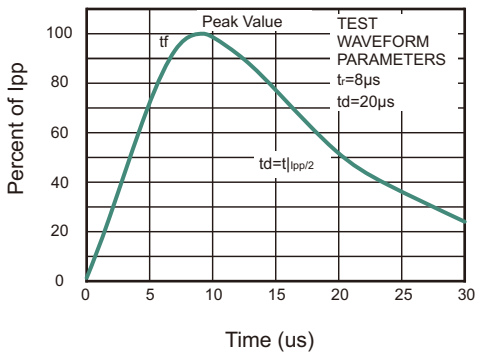
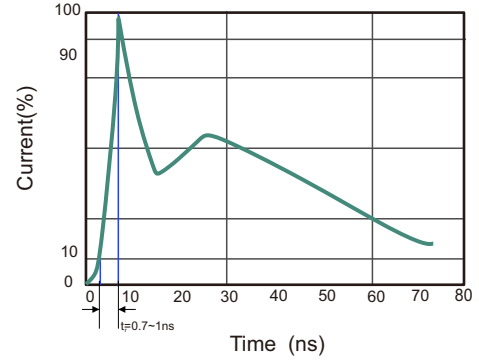
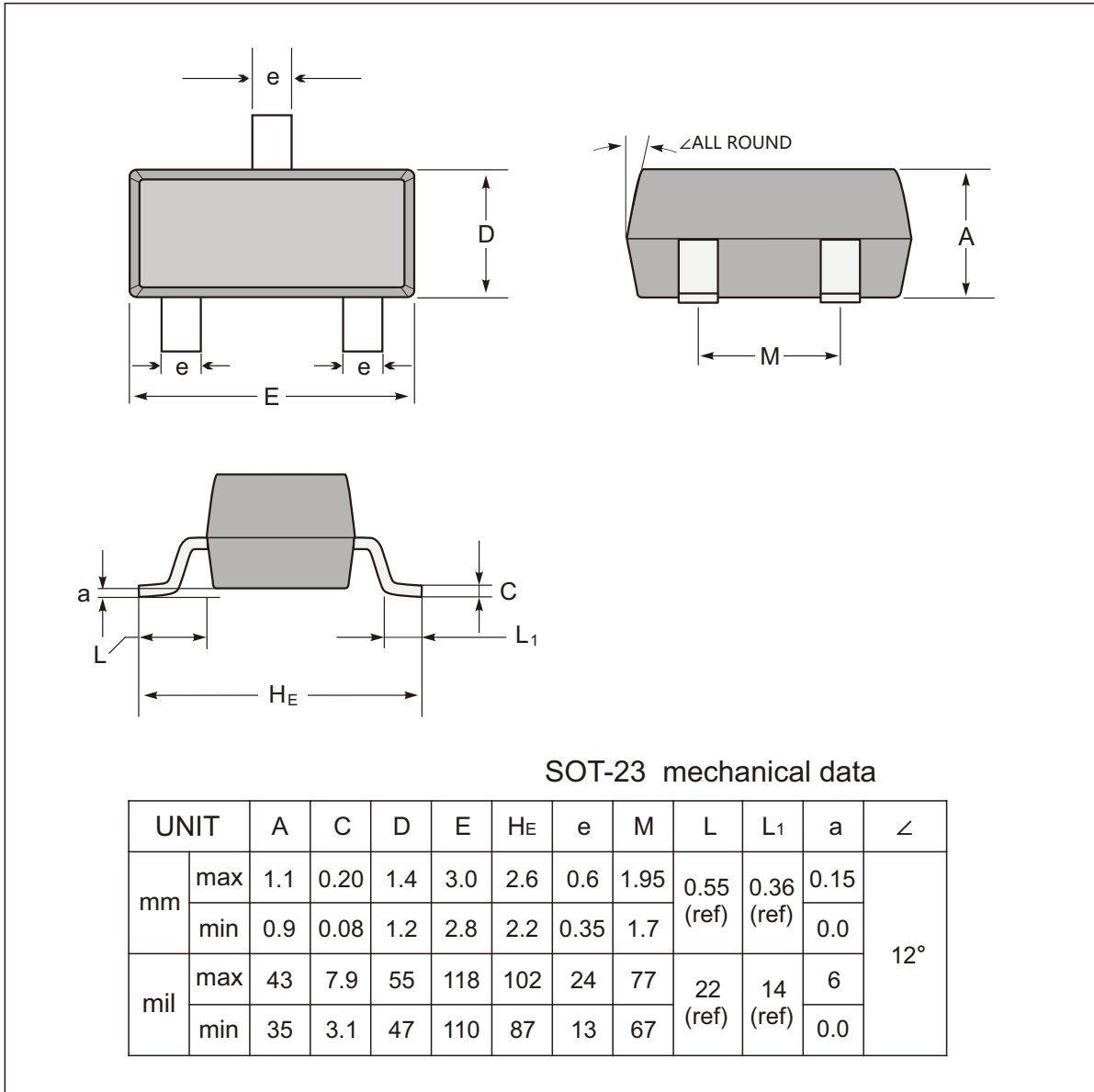


Fig.6 Contact discharge current waveform per IEC61000-4-2

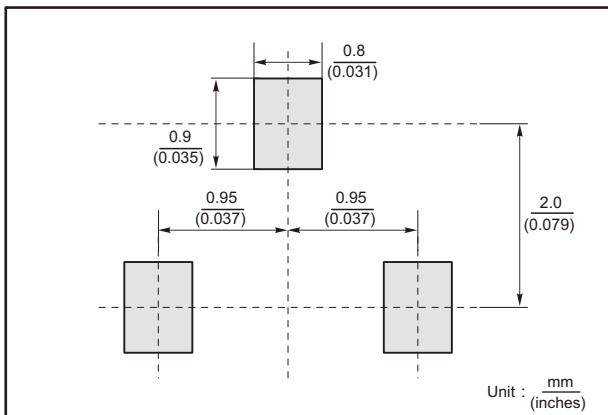




### SOT-23 Package Outline Dimensions



#### The recommended mounting pad size



#### Marking

Type number	Marking code
ESDB18V0T2CA	2K



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